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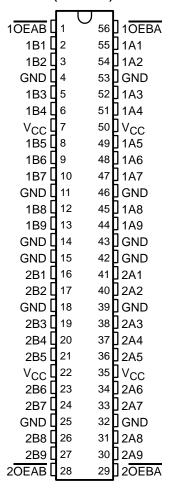
- **Members of the Texas Instruments** Widebus™ Family
- State-of-the-Art *EPIC-IIB™* BiCMOS Design Significantly Reduces Power Dissipation
- Latch-Up Performance Exceeds 500 mA Per **JEDEC Standard JESD-17**
- Typical V_{OLP} (Output Ground Bounce) < 1 V at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$
- **High-Impedance State During Power Up** and Power Down
- Distributed V_{CC} and GND Pin Configuration **Minimizes High-Speed Switching Noise**
- Flow-Through Architecture Optimizes PCB Layout
- High-Drive Outputs (-32-mA IOH, 64-mA IOI)
- Package Options Include Plastic 300-mil Shrink Small-Outline (DL) Package and 380-mil Fine-Pitch Ceramic Flat (WD) Package Using 25-mil Center-to-Center Spacings

description

'ABT16863 The 18-bit noninverting are transceivers designed for asynchronous communication between data buses. The control-function implementation minimizes external timing requirements.

The 'ABT16863 can be used as two 9-bit transceivers or one 18-bit transceiver. They allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the output-enable (OEAB or OEBA) inputs.

SN54ABT16863...WD PACKAGE SN74ABT16863 . . . DL PACKAGE (TOP VIEW)



When V_{CC} is between 0 and 2.1 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 2.1 V, $\overline{\text{OE}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54ABT16863 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74ABT16863 is characterized for operation from -40°C to 85°C.



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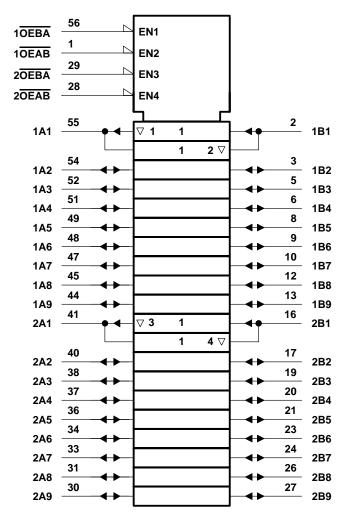


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FUNCTION TABLE (each 9-bit section)

INP	UTS	OPERATION					
OEAB	OEBA						
Н	L	B data to A bus					
L	Н	A data to B bus					
Н	Н	Isolation					

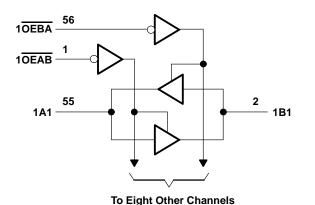
logic symbol†

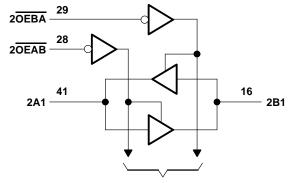


[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



logic diagram (positive logic)





To Eight Other Channels

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	–0.5 V to 7 V
Input voltage range, V _I (except I/O ports) (see Note 1)	0.5 V to 7 V
Voltage range applied to any output in the high or power-off state, VO	0.5 V to 5.5 V
Current into any output in the low state, IO: SN54ABT16863	96 mA
SN74ABT16863	128 mA
Input clamp current, $I_{ K }(V_{ } < 0)$	–18 mA
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Package thermal impedance, θ _{JA} (see Note 2): DL package	74°C/W
Storage temperature range, T _{stg}	. −65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with EIA/JEDEC Std JESD51.

recommended operating conditions (see Note 3)

			SN54ABT	16863	SN74ABT16863		UNIT
			MIN	MAX	MIN	MAX	UNIT
Vcc	V _{CC} Supply voltage				4.5	5.5	V
V _{IH} High-level input voltage				N	2		V
V _{IL}	V _{IL} Low-level input voltage					0.8	V
VI	Input voltage				0	VCC	V
IOH	I _{OH} High-level output current		4	-24		-32	mA
lOL	Low-level output current		770	48		64	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled	06	10		10	ns/V
Δt/ΔVCC	Power-up ramp rate		200		200	·	μs/V
T _A	Operating free-air temperature		-55	125	-40	85	°C

NOTE 3: Unused pins (input or I/O) must be held high or low to prevent them from floating.

SN54ABT16863, SN74ABT16863 18-BIT BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A = 25°C			SN54ABT16863		SN74ABT16863		UNIT	
				MIN	TYP†	MAX	MIN	MAX	MIN	MAX	UNIT	
VIK		$V_{CC} = 4.5 \text{ V},$	I _I = -18 mA			-1.2		-1.2		-1.2	V	
		$V_{CC} = 4.5 \text{ V},$	$I_{OH} = -3 \text{ mA}$	2.5			2.5		2.5			
\ \/a		$V_{CC} = 5 V$,	$I_{OH} = -3 \text{ mA}$	3			3		3		V	
VOH		V _{CC} = 4.5 V	$I_{OH} = -24 \text{ mA}$	2			2				v	
		VCC = 4.5 V	$I_{OH} = -32 \text{ mA}$	2*					2			
VOL		V _{CC} = 4.5 V	I _{OL} = 48 mA			0.55		0.55			V	
VOL		VCC = 4.5 V	I _{OL} = 64 mA			0.55*				0.55		
V _{hys}					100						mV	
	Control inputs	$V_{CC} = 0 \text{ to } 5.5 \text{ V, V}$	I = V _{CC} or GND			±1		±1		±1		
lį	A or B ports	$V_{CC} = 2.1 \text{ V to } 5.5 \text{ V}$ $V_{I} = V_{CC} \text{ or GND}$	J,			±20		±20		±20	μΑ	
lozpu‡	:	$V_{CC} = 0 \text{ to } 2.1 \text{ V},$ $V_{O} = 0.5 \text{ V to } 2.7 \text{ V}, \overline{OE} = X$				±50		±50		±50	μΑ	
$V_{CC} = 2.1 \text{ V to } 0,$ $V_{O} = 0.5 \text{ V to } 2.7 \text{ V},$		OE = X			±50		±50		±50	μΑ		
$V_{CC} = 2.1 \text{ V to } 5.5 \text{ V},$ $V_{O} = 2.7 \text{ V}, \overline{OE} \ge 2 \text{ V}$		V, V			10	Q /2	10		10	μΑ		
lozL§	OZL§ $V_{CC} = 2.1 \text{ V to } 5.5 \text{ V}, \\ V_{O} = 0.5 \text{ V}, \overline{OE} \ge 2 \text{ V}$		V, V			-10	7908	-10		-10	μА	
l _{off}		$V_{CC} = 0$,	V_I or $V_O \le 4.5 \text{ V}$			±100	Q			±100	μΑ	
ICEX	Outputs high	$V_{CC} = 5.5 \text{ V},$	V _O = 5.5 V			50		50		50	μΑ	
ΙΟ [¶]		$V_{CC} = 5.5 \text{ V},$	V _O = 2.5 V	-50	-100	-180	-50	-180	-50	-180	mA	
		$V_{CC} = 5.5 \text{ V},$ $V_{O} = 0,$ $V_{I} = V_{CC} \text{ or GND}$	Outputs high			2		2		2		
Icc	A or B ports		Outputs low			32		32		32	mA	
			Outputs disabled			2		2		2		
		$\begin{array}{c} V_{CC} = 5.5 \text{ V}, \\ \text{One input at} \\ 3.4 \text{ V}, \\ \text{Other inputs at} \\ V_{CC} \text{ or GND} \end{array}$	Outputs enabled			1		1.5		1		
Δl _{CC} #	Data Inputs		Outputs disabled	_		0.05		0.05		0.05	mA	
	Control inputs	V _{CC} = 5.5 V, One ir Other inputs at V _{CC}				1.5		1.5		1.5		
Ci	Control inputs	V _I = 2.5 V or 0.5 V			3.5						pF	
C _{io}	A or B ports	V _O = 2.5 V or 0.5 V			9.5						pF	

^{*} On products compliant to MIL-PRF-38535, this parameter does not apply.



[†] All typical values are at $V_{CC} = 5 \text{ V}$.

[‡] This parameter is characterized, but not production tested.

[§] The parameters IOZH and IOZL include the input leakage current.

Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

[#] This is the increase in supply current for each input that is at the specified TTL voltage level rather than VCC or GND.

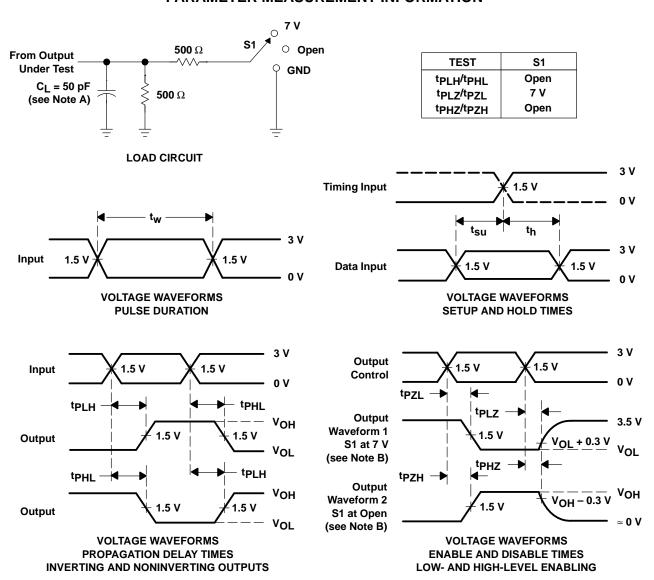
SN54ABT16863, SN74ABT16863 18-BIT BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

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switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 5 V, T _A = 25°C			SN54ABT16863		SN74ABT16863		UNIT
	(INFOT)		MIN	TYP	MAX	MIN	MAX	MIN	MAX	
^t PLH	A or B	B or A	1	2.2	3.2	1	3.7	1	3.5	no
t _{PHL}	AUID	BULA	1	2.2	3.4	1 2	4.2	1	3.9	ns
^t PZH	OFDA OFAR	A or B	1	2.9	4.5	10	5.7	1	5.4	20
t _{PZL}	OEBA or OEAB	AOIB	1	2.6	4.1	3	5.2	1	4.8	ns
^t PHZ	OEBA or OEAB	A or D	1.6	4.1	5.4	01.6	6.3	1.6	6	ns ns
t _{PLZ}		OEBA or OEAB A or B	1.5	3.3	4.5	1.5	5.3	1.5	5	

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , $t_f \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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